

SCHOTTKY BARRIER RECTIFIERS

REVERSE VOLTAGE - 70 to 100 Volts
FORWARD CURRENT - 10 Amperes

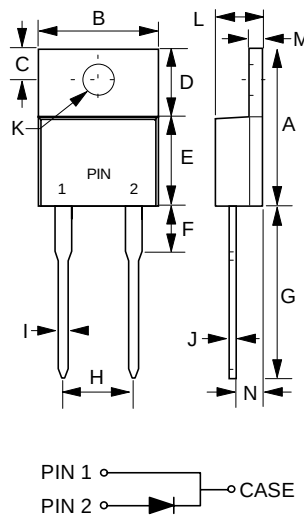
FEATURES

- Metal of silicon rectifier, majority carrier conduction
- Guard ring for transient protection
- Low power loss, high efficiency
- High current capability, low VF
- High surge capacity
- Plastic package has UL flammability classification 94V-0
- For use in low voltage, high frequency inverters, free wheeling, and polarity protection applications

MECHANICAL DATA

- Case : TO-220AC molded plastic
- Polarity : As marked on the body
- Weight : 0.08 ounces, 2.24 grams
- Mounting position : Any

TO-220AC



TO-220AC		
DIM.	MIN.	MAX.
A	14.22	15.88
B	9.65	10.67
C	2.54	3.43
D	5.84	6.86
E	8.26	9.28
F	-	6.35
G	12.70	14.73
H	4.83	5.33
I	0.51	1.14
J	0.30	0.64
K	3.53 $\varnothing$	4.09 $\varnothing$
L	3.56	4.83
M	1.14	1.40
N	2.03	2.92

All Dimensions in millimeter

MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Ratings at 25°C ambient temperature unless otherwise specified.
Single phase, half wave, 60Hz, resistive or inductive load.
For capacitive load, derate current by 20%

CHARACTERISTICS	SYMBOL	MBR1070	MBR1080	MBR1090	MBR10100	UNIT
Maximum Recurrent Peak Reverse Voltage	V _{RRM}	70	80	90	100	V
Maximum RMS Voltage	V _{RMS}	49	56	63	70	V
Maximum DC Blocking Voltage	V _{DC}	70	80	90	100	V
Maximum Average Forward Rectified Current (See Fig.1) @T _C =135°C	I _(AV)	10				A
Peak Forward Surge Current 8.3ms single half sine-wave superimposed on rated load (JEDEC METHOD)	I _{FSM}	150				A
Voltage Rate of Change (Rated VR)	dv/dt	10000				V/us
Maximum Forward Voltage (Note 1) I _F =10A @ T _J =25°C I _F =10A @ T _J =125°C I _F =20A @ T _J =125°C	V _F	0.85 0.75 0.80				V
Maximum DC Reverse Current at Rated DC Blocking Voltage @T _J =25°C @T _J =125°C	I _R	0.1 100				mA
Typical Thermal Resistance (Note 2)	R _{θJC}	2.0				°C/W
Typical Junction Capacitance (Note 3)	C _J	1100				pF
Operating Temperature Range	T _J	-55 to +150				°C
Storage Temperature Range	T _{STG}	-55 to +175				°C

NOTES : 1.300us Pulse Width, 2% Duty Cycle.
2.Thermal Resistance Junction to Case.
3.Measured at 1.0MHz and applied reverse voltage of 4.0V DC.

REV. 0, 04-Mar-2002, KTHA12

FIG.1 - FORWARD CURRENT DERATING CURVE

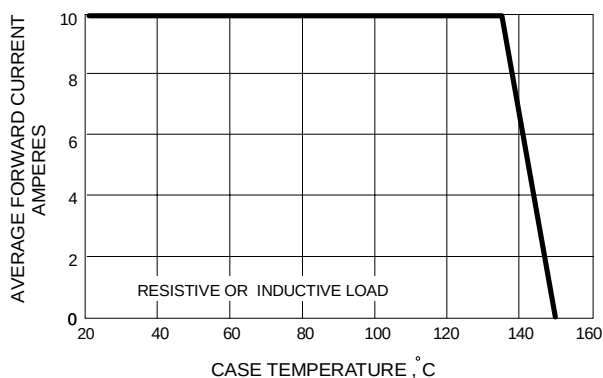


FIG.2 - MAXIMUM NON-REPETITIVE SURGE CURRENT

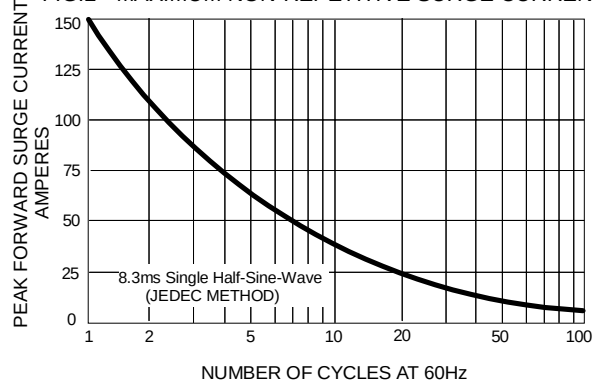


FIG.3 - TYPICAL REVERSE CHARACTERISTICS

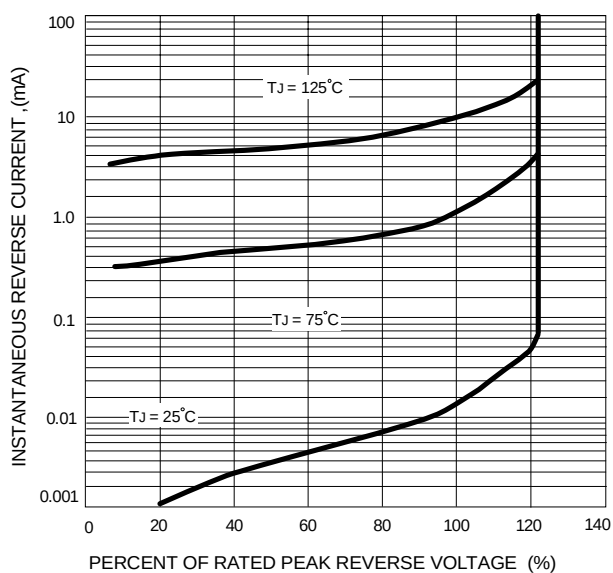


FIG.4 - TYPICAL FORWARD CHARACTERISTICS

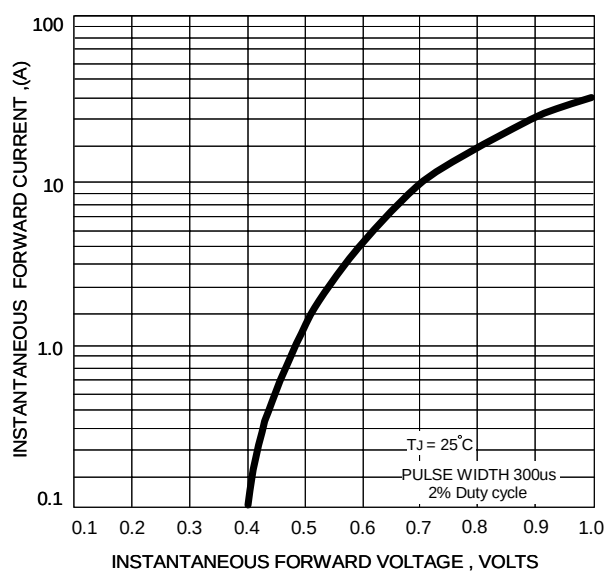


FIG.5 - TYPICAL JUNCTION CAPACITANCE

